

50MHz to 3GHz RF Power Detector with 60dB Dynamic Range

FEATURES

- RF Frequency Range: 50MHz to 3GHz
- Linear Dynamic Range: 60dB
- Exceptional Accuracy over Temperature and Power Supply
- Fast Transient Response:
38ns Full-Scale Settling Time
- Single 2.7V to 5.25V Supply
- Low Supply Current: 7mA
- Shutdown Current: 0.1 μ A
- Tiny 6-Lead SC70 Package

APPLICATIONS

- RF RSSI and ACC
- RF Power Control
- CATV Power Detection
- Optical Receiver Gain Control

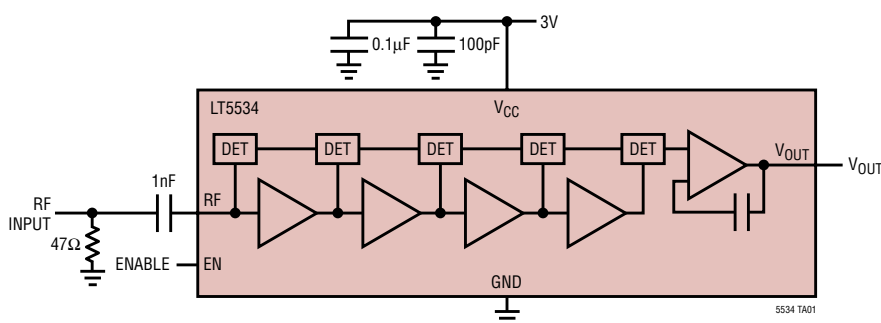
DESCRIPTION

The LT[®]5534 is a 50MHz to 3GHz monolithic RF power detector capable of measuring RF signals over a 60dB dynamic range. The RF signal in a decibel scale is precisely converted into DC voltage on a linear scale. The 60dB input dynamic range is achieved using cascaded RF detectors and RF limiters. Their outputs are summed to generate an accurate log-linear DC voltage proportional to the input RF signal in dB. The output is buffered with a low output impedance driver. The LT5534 delivers superior temperature stability (typical output variation within ± 1 dB over the full temperature range). The output responds in less than 40ns to a large RF input signal.

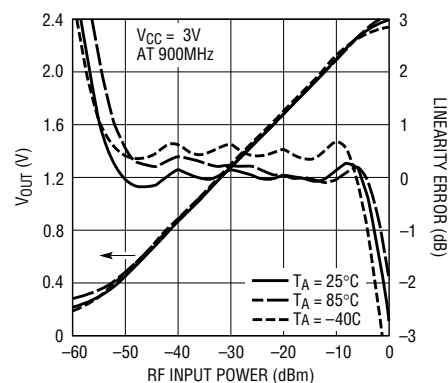
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TYPICAL APPLICATION

50MHz to 3GHz RF Power Detector



Output Voltage
vs RF Input Power

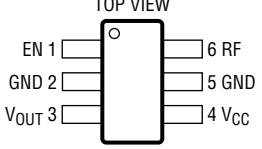


ABSOLUTE MAXIMUM RATINGS

(Note 1)

Power Supply Voltage	5.5V
Enable Voltage	0V, V_{CC}
RF Voltage (+10dBm Equivalent)	$\pm 1V$
Operating Ambient Temperature Range ..	-40°C to 85°C
Storage Temperature Range	-65°C to 125°C
Lead Temperature (Soldering, 10 sec)	300°C

PACKAGE/ORDER INFORMATION

 SC6 PACKAGE 6-LEAD PLASTIC SC70 $T_{JMAX} = 125^{\circ}\text{C}$, $\theta_{JA} = 256^{\circ}\text{C/W}$	ORDER PART NUMBER
	LT5534ESC6
	SC6 PART MARKING
	LBGD
Order Options Tape and Reel: Add #TR Lead Free: Add #PBF Lead Free Tape and Reel: Add #TRPBF Lead Free Part Marking: http://www.linear.com/leadfree/ Consult LTC Marketing for parts specified with wider operating temperature ranges.	

ELECTRICAL CHARACTERISTICS

$V_{CC} = 3V$, $EN = 3V$, $T_A = 25^{\circ}\text{C}$, source impedance = 50Ω , unless otherwise noted. Test circuit shown in Figure 1. (Note 2)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
RF Input					
Frequency Range			50 to 3000		MHz
Input Impedance			2		$k\Omega$
$f_{RF} = 50\text{MHz}$					
RF Input Power Range			-58 to $+2$		dBm
Dynamic Range (Note 3)	$\pm 3\text{dB}$ Linearity Error, $T_A = -40^{\circ}\text{C}$ to 85°C		60		dB
Output Slope			44		mV/dB
Output Variation vs Temperature	$P_{IN} = -48\text{dBm}$ to -14dBm , $T_A = -40^{\circ}\text{C}$ to 85°C		0.007		dB/ $^{\circ}\text{C}$
$f_{RF} = 900\text{MHz}$					
RF Input Power Range			-60 to 0		dBm
Dynamic Range (Note 3)	$\pm 3\text{dB}$ Linearity Error, $T_A = -40^{\circ}\text{C}$ to 85°C		60		dB
Output Slope			41		mV/dB
Output Variation vs Temperature	$P_{IN} = -48\text{dBm}$ to -14dBm , $T_A = -40^{\circ}\text{C}$ to 85°C		0.008		dB/ $^{\circ}\text{C}$
$f_{RF} = 1900\text{MHz}$					
RF Input Power Range			-63 to -2		dBm
Dynamic Range (Note 3)	$\pm 3\text{dB}$ Linearity Error, $T_A = -40^{\circ}\text{C}$ to 85°C		61		dB
Output Slope		31	36.6	43	mV/dB
Output Variation vs Temperature	$P_{IN} = -48\text{dBm}$ to -14dBm , $T_A = -40^{\circ}\text{C}$ to 85°C		0.012		dB/ $^{\circ}\text{C}$
Output Intercept	50Ω External Termination, $T_A = -40^{\circ}\text{C}$ to 85°C	-70	-64	-58	dBm
$f_{RF} = 2500\text{MHz}$					
RF Input Power Range			-63 to -3		dBm
Dynamic Range (Note 3)	$\pm 3\text{dB}$ Linearity Error, $T_A = -40^{\circ}\text{C}$ to 85°C		60		dB
Output Slope			35		mV/dB
Output Variation vs Temperature	$P_{IN} = -48\text{dBm}$ to -14dBm , $T_A = -40^{\circ}\text{C}$ to 85°C		0.025		dB/ $^{\circ}\text{C}$
Output Interface					
Output DC Voltage	No RF Input Signal	30	142	240	mV
Output Impedance			32		Ω
Output Bandwidth			30		MHz
Full-Scale Setting Time	Input from No Signal to -2dBm , to 90%		38		ns
Sinking/Sourcing			10/200		mA/ μA

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ELECTRICAL CHARACTERISTICS

$V_{CC} = 3V$, $EN = 3V$, $T_A = 25^\circ C$, unless otherwise noted.
Test circuit shown in Figure 1. (Note 2)

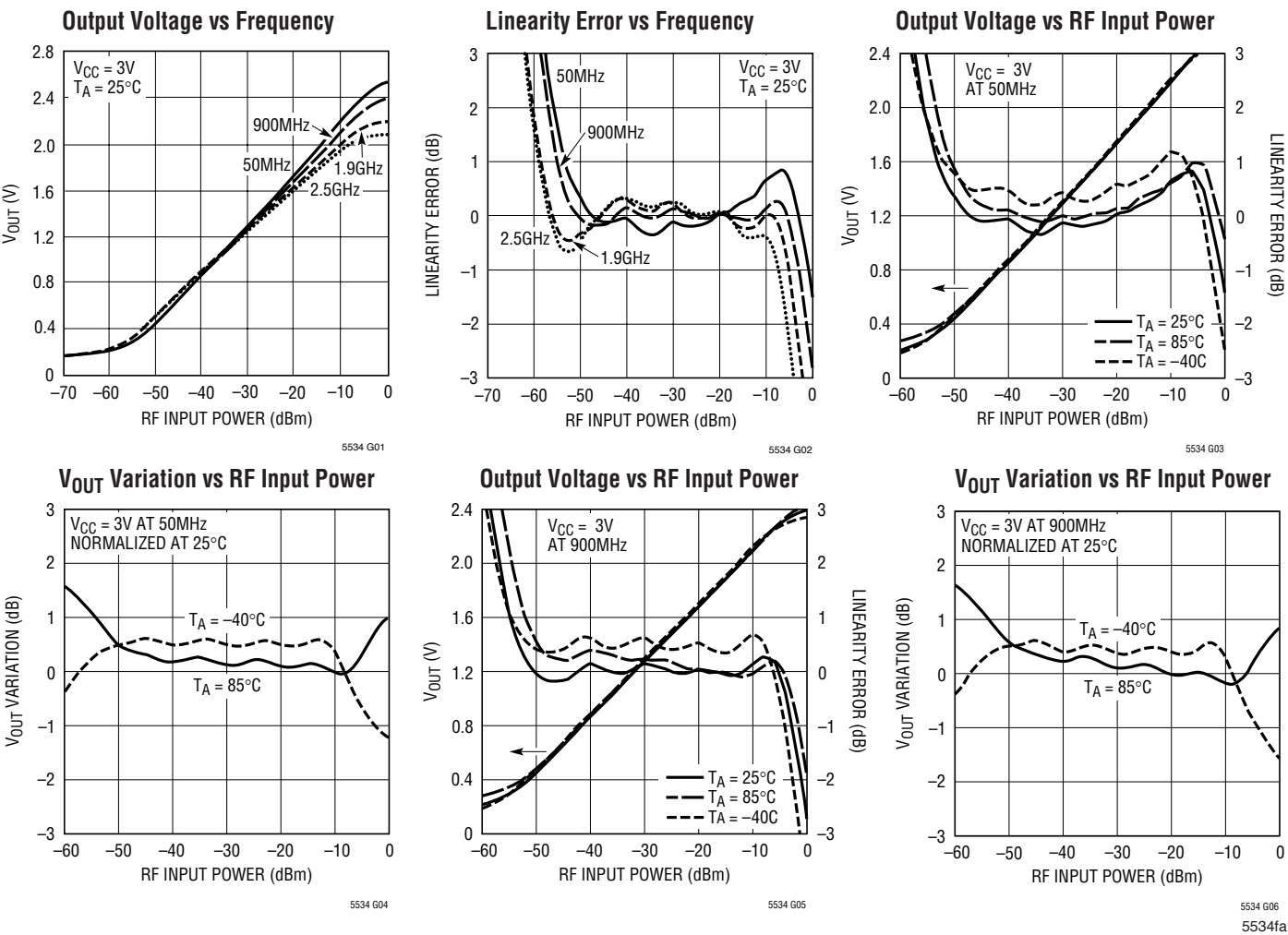
PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Power Up/Down					
Turn-On Time			200		ns
Turn-Off Time			800		ns
EN = High (On)		0.9			V
EN = Low (Off)				0.6	V
Power Supply					
Supply Voltage		2.7		5.25	V
Supply Current	EN = High	5	7	9	mA
Shutdown Current	EN = Low		0.1	10	μA

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

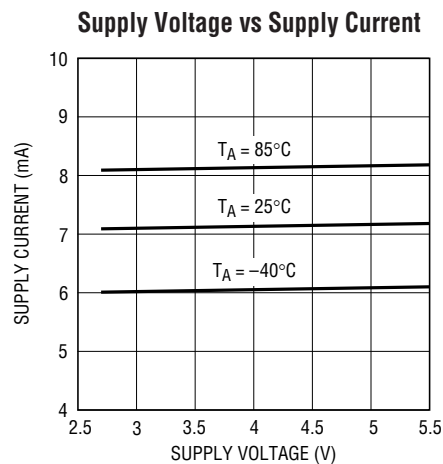
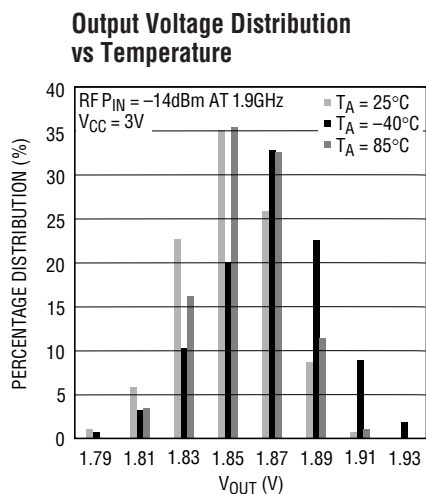
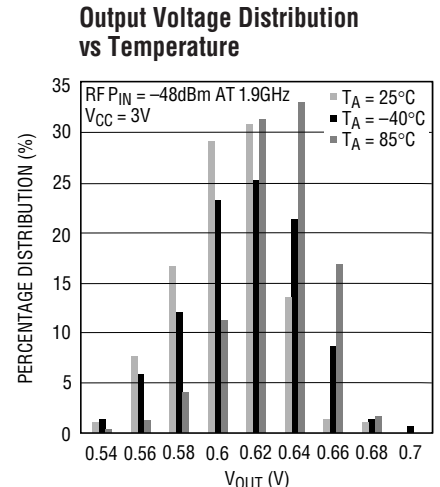
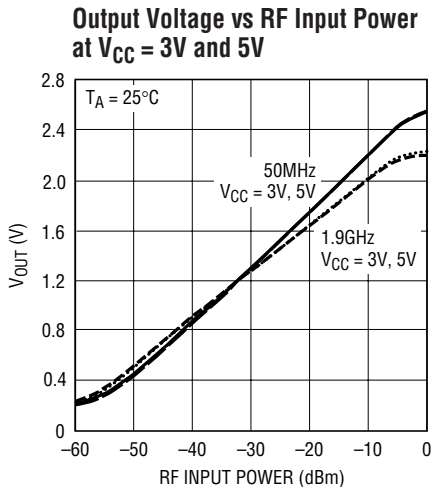
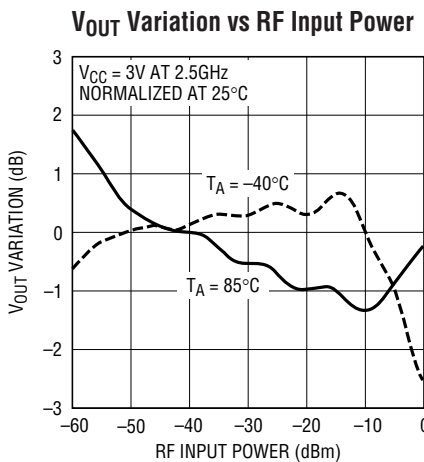
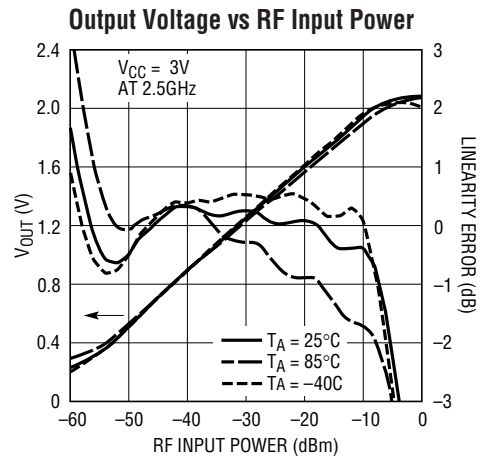
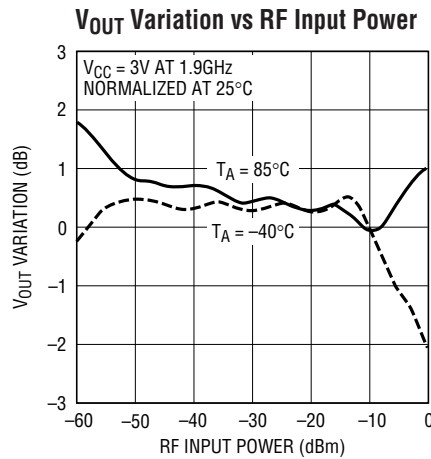
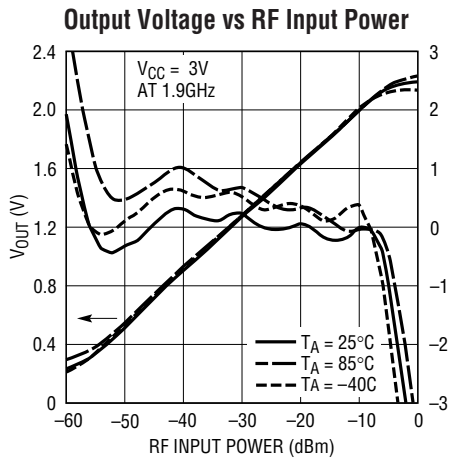
Note 2: Specifications over the $-40^\circ C$ to $85^\circ C$ temperature range are assured by design, characterization and correlation with statistical process control.

Note 3: The linearity error is calculated by the difference between the incremental slope of the output and the average output slope from $-48dBm$ to $-14dBm$. The dynamic range is defined as the range over which the linearity error is within $\pm 3dB$.

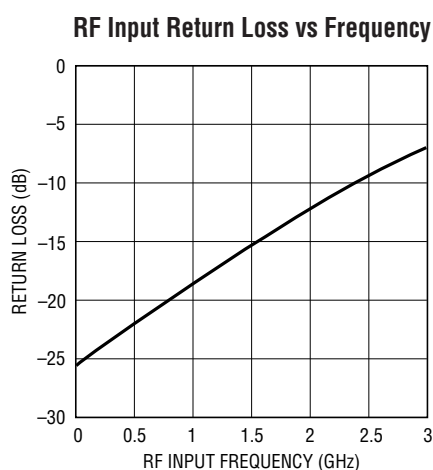
TYPICAL PERFORMANCE CHARACTERISTICS (Test circuit shown in Figure 1)



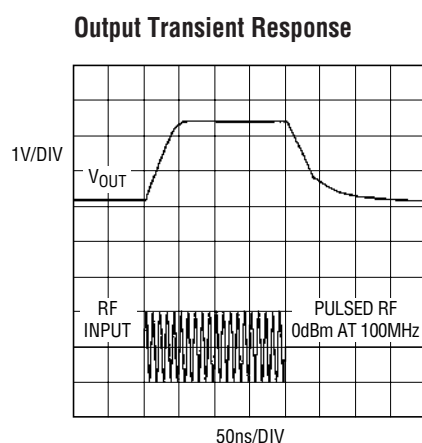
TYPICAL PERFORMANCE CHARACTERISTICS (Test circuit shown in Figure 1)



TYPICAL PERFORMANCE CHARACTERISTICS (Test circuit shown in Figure 1)



5534 G15



5534 G16

PIN FUNCTIONS

EN (Pin 1): Enable. When the input voltage is higher than 0.9V, the circuit is completely turned on. When the input voltage is less than 0.6V, the circuit is turned off.

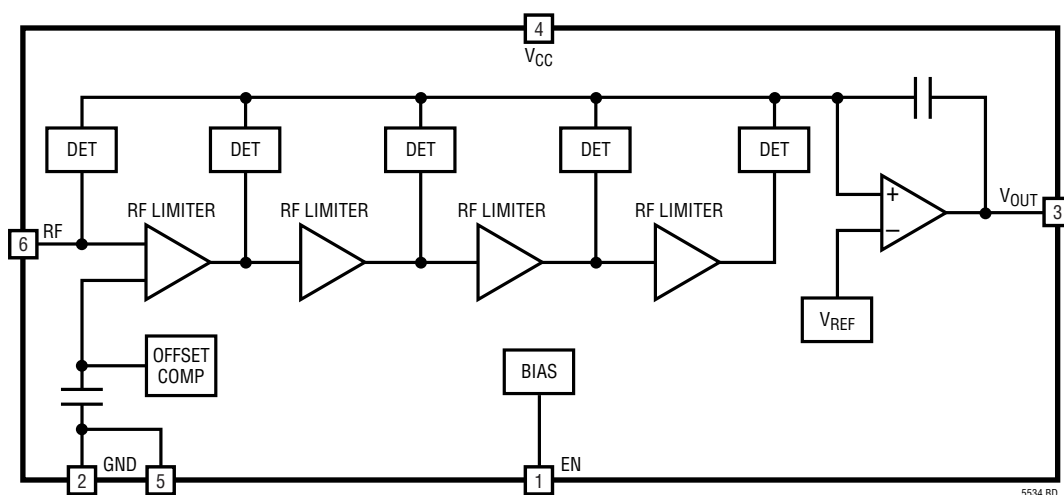
GND (Pins 2, 5): Ground.

V_{OUT} (Pin 3): RF Detector Output.

V_{CC} (Pin 4): Power Supply. This pin should be decoupled using 100pF and 0.1μF capacitors.

RF (Pin 6): RF input. This pin is internally biased to $V_{CC} - 0.18V$. A coupling capacitor must be used to connect to the RF signal source.

BLOCK DIAGRAM



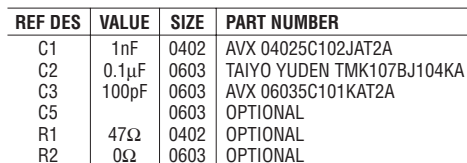


Figure 1. Evaluation Circuit Schematic

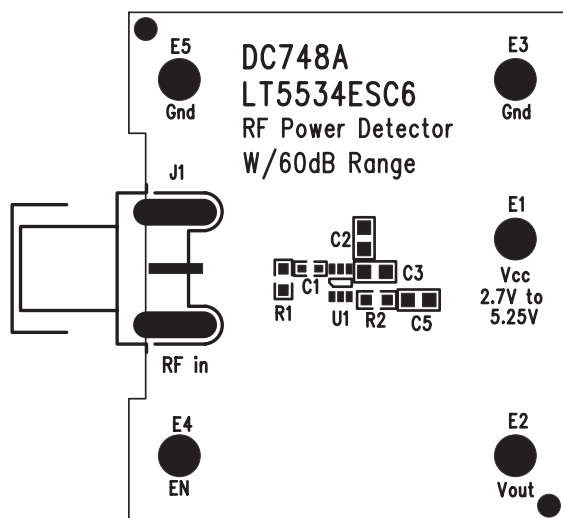


Figure 2. Component Side Silkscreen of Evaluation Board

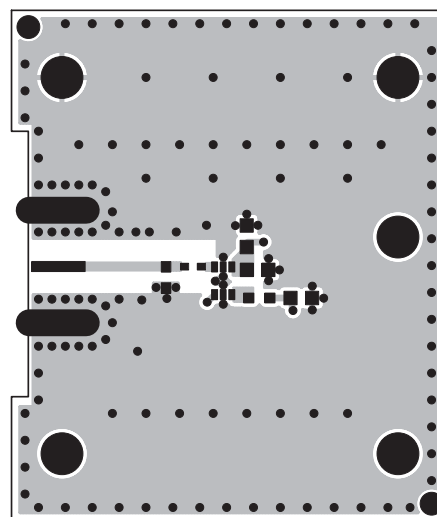


Figure 3. Component Side Layout of Evaluation Board

APPLICATIONS INFORMATION

RF Input Port

matching components. A 47Ω resistor (R1) connected to ground will provide better than 10dB input return loss up to 2.5GHz. An additional 2nH inductance in series with R1 will provide improved input matching up to 3GHz. The impedance vs frequency of the RF input is detailed in Table 1.

The approximate linear RF input power range of the LT5534 is from -62dBm to -2dBm with a 50Ω source impedance. However, this range can be adjusted either upward or downward to tailor for a particular application

APPLICATIONS INFORMATION

Table 1. RF Input Impedance

FREQUENCY (MHz)	INPUT IMPEDANCE (Ω)	S11	
		MAG	ANGLE (DEG)
50	1429-j429	0.938	-1.1
100	947-j710	0.934	-2.9
200	509-j609	0.922	-5.6
400	250-j440	0.908	-9.9
600	149-j344	0.900	-14.1
800	96.8-j278	0.896	-18.3
1000	67.6-j229	0.893	-22.7
1200	49.7-j193	0.889	-27.3
1400	38.4-j165	0.883	-32.3
1600	30.8-j143	0.879	-37.3
1800	25.4-j125	0.873	-42.6
2000	21.4-j109	0.866	-48.0
2200	18.5-j96.2	0.862	-53.6
2400	16.6-j85.0	0.848	-59.6
2600	15.2-j75.7	0.834	-65.6
2800	13.7-j67.5	0.826	-71.8
3000	12.1-j60.1	0.822	-78.2

need. By simply inserting an attenuator in front of the RF input, the power range is shifted higher by the amount of the attenuation. Moreover, due to the high RF input impedance of the LT5534, the detecting range can be moved downward for better detection sensitivity by using a narrow band L-C matching network. By this means, the sensitivity of the detector can be extended to as low as -75dBm. By changing the value of resistor R1, the sensitivity of the detector can be fine-tuned within the range from -75dBm to -62dBm. Though the range is adjustable, the overall linear dynamic range remains the same.

Output Interface

The output interface of the LT5534 is shown in Figure 4. The output currents from the RF detectors are summed and converted into an output voltage, V_{OUT} . The maximum charging current available to the output load is about 200 μ A. The internal compensation capacitor C_C is used to guarantee stable operation for a large capacitive output load. The slew rate is 133V/ μ s, and the small-signal output bandwidth is approximately 30MHz when the output is resistively

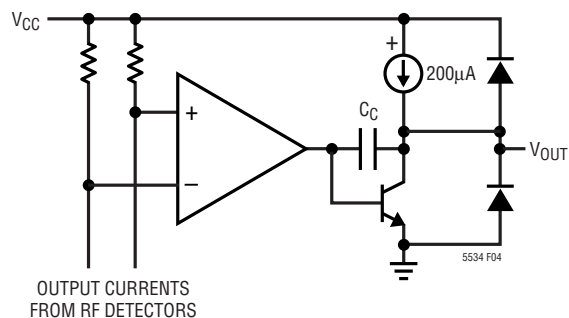


Figure 4. Simplified Circuit Schematic of the Output Interface

terminated or open. The fastest output transient response is achieved when a large signal is applied to the RF input port. See the output transient response plot in the Typical Performance Characteristics section.

When the output is terminated with a load capacitance C_L , the slew rate is then limited to $200\mu\text{A}/(C_L + 1.5\text{pF})$. For example, the slew rate is reduced to 17.4V/ μ s when $C_L = 10\text{pF}$. A capacitive load may result in output voltage overshoot, which can be minimized with a series compensation resistor R2 as shown in Figure 1. The suggested resistor values for various capacitive loads are listed in Table 2.

Table 2. Resistor Value for Capacitive Output

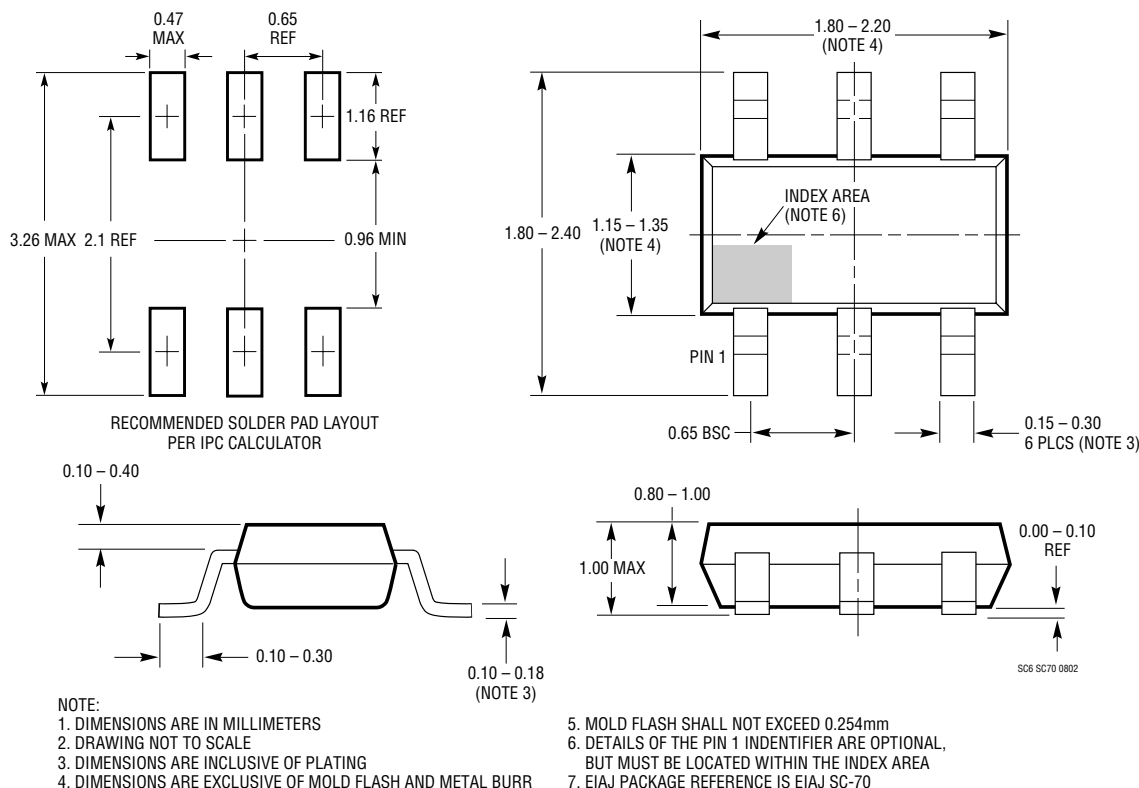
C5 (pF)	R2 (k Ω)
1.5	5
5	4
10	2.5
20	2

The optional RC network at the output (R2 and C5 on the demo board) can also provide further output filtering, if needed. The output bandwidth is primarily dictated by the RC constant of this lowpass filter when its corner frequency is less than 30MHz.

When a large signal (e.g., -2dBm) is present at the RF input port, the output voltage swing can be as high as 2.4V. To assure proper operation of the chip, the minimum resistive load at the output termination should be greater than 18k Ω .

PACKAGE DESCRIPTION

SC6 Package
6-Lead Plastic SC70
 (Reference LTC DWG # 05-08-1638)



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT5504	800MHz to 2.7GHz RF Measuring Receiver	80dB Dynamic Range, Temperature Compensated, 2.7V to 5.25V Supply
LT5506	500MHz Quadrature IF Demodulator with VGA	1.8V to 5.25V Supply, 40MHz to 500MHz IF, -4dB to 57dB Linear Power Gain, 8.8MHz Baseband Bandwidth
LT5511	High Linearity Upconverting Mixer	RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer
LT5512	DC-3GHz High Signal Level Downconverting Mixer	DC to 3GHz, 21dBm IIP3, Integrated LO Buffer
LT5515	1.5GHz to 2.5GHz Direct Conversion Quadrature Demodulator	20dBm IIP3, Integrated LO Quadrature Generator
LT5516	0.8GHz to 1.5GHz Direct Conversion Quadrature Demodulator	21.5dBm IIP3, Integrated LO Quadrature Generator
LT5517	40MHz to 900MHz Direct Conversion Quadrature Demodulator	21dBm IIP3, Integrated LO Quadrature Generator
LT5519	0.7GHz to 1.4GHz High Linearity Upconverting Mixer	17.1dBm IIP3, 50Ω Single Ended RF and LO Ports
LT5520	1.3GHz to 2.3GHz High Linearity Upconverting Mixer	15.9dBm IIP3, 50Ω Single Ended RF and LO Ports
LT5522	600MHz to 2.7GHz High Linearity Downconverting Mixer	4.5V to 5.25V Supply, 25dBm IIP3 at 900MHz, NF = 12.5dB, 50Ω Single Ended RF and LO Ports
LTC®5532	300MHz to 7GHz Precision RF Power Detector	Precision V_{OUT} Offset Control, Adjustable Gain and Offset
LT5546	500MHz Quadrature IF Demodulator with VGA and 17MHz Baseband Bandwidth	17MHz Baseband Bandwidth, 40MHz to 500MHz IF, 1.8V to 5.25V Supply, -7dB to 56dB Linear Power Gain

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